



& ROOHFWRU 1 % DVH 9 ROWDJH	9
& ROOHFWRU 2 % DVH 9 ROWDJH	9
(PLWWHU % DVH 9 ROWDJH	9
& ROOHFWRU 3 % DVH 9 ROWDJH	\$
& ROOHFWRU 3 RZHU 'LVVLSDWL	:
7KHUPDO 5HVRW XQFWM LIRQ WR \$ PELHQW	/ :
-XQFWL RQDWHXPUH	/
6WRUDJH 7HPSHUDWXUH	/

Collector-base breakdown voltage	$V_{(BR)CBO}$		9
Collector-emitter breakdown voltage	$V_{(BR)CEO}$		9
Emitter-base breakdown voltage	$V_{(BR)EBO}$		9
Collector cut-off current	I_{C0}	$I_{C0} = 9 \mu A$	9
Collector cut-off current	I_{C0}	$I_{C0} = 9 \mu A$	9
Emitter cut-off current	I_{E0}	$I_{E0} = 9 \mu A$	9
DC current gain	K_{DC}	$V_{CE}=5V, I_C=1A$	9
	K_{DC}	$V_{CE}=5V, I_C=200mA$	9
	K_{DC}	$V_{CE}=5V, I_C=10mA$	9
	K_{DC}	$V_{CE}=5V, I_C=10mA$	9
Collector-emitter saturation voltage	$V_{CE(sat)}$		9
Base-emitter saturation voltage	$V_{BE(sat)}$		9
	$V_{BE(sat)}$		9
Diode forward voltage	V_{D0}		9
Transition frequency	f_T	$V_{CE}=10V, I_C=0.5A, f=1MHz$	5
Rise time	t_r	$I_C=250mA$	0 +]
Storage time	t_s	$I_C=250mA$	— V
Fall time	t_f	$I_C=250mA$	

